

SSCN2222AGS7

High Frequency High Gain NPN Power BJT

Features

| VCB | VCE | VEB | IC | |
|-----|-----|-----|-------|--|
| 75V | 40V | 6V | 600mA | |

Description

This product is general usage and suitable for many different applications. It can be used for medium power amplifiers and switches requiring collector currents up to 600 mA.

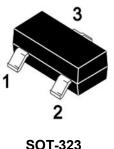
Applications

- Low current and high precision circuits such preamplifiers, oscillators, current mirror configuration
- Medium power amplification and switching

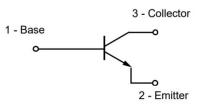
Ordering Information

| Device | Package | Shipping | |
|--------------|---------|-----------|--|
| SSCN2222AGS7 | SOT-323 | 3000/Reel | |

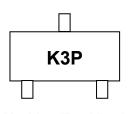
Pin configuration



SOT-323



Circuit Diagram



Marking(Top View)



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ightarrow Absolute Maximum Ratings(T_A=25°C unless otherwise noted)

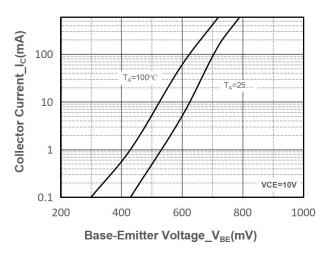
| Parameter | Symbol | Value | Unit | |
|------------------------------|---------------------|------------|------------|--|
| Collector-Base Voltage | V _{CBO} | 75 | V | |
| Collector- Emitter Voltage | V _{CEO} 40 | | | |
| Emitter-Base Voltage | V _{EBO} | 6 | V | |
| Collector Current-Continuous | Ic | 600 | mA | |
| Collector Power Dissipation | Pc | 200 | mW | |
| Junction Temperature | T _J 150 | | $^{\circ}$ | |
| Storage Temperature | T _{STG} | -55 to 150 | $^{\circ}$ | |

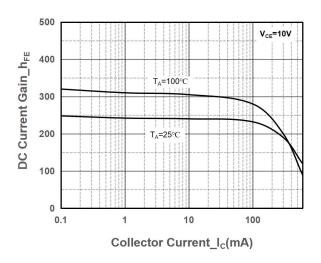
➤ Electrical Characteristics (T_A=25°C unless otherwise noted)

| Parameter | Symbol | Test Conditions | Min. | Тур. | Max. | Unit |
|--------------------------------------|----------------------|---|------|------|------|-------|
| Collector-Base Breakdown Voltage | BV _{CBO} | I _C =0.1mA,I _E =0 | 75 | | | V |
| Collector-emitter Breakdown Voltage | BV _{CEO} | I _C =1mA,I _B =0 | 40 | | | V |
| Emitter -Base Breakdown Voltage | BV _{EBO} | I _E =0.1mA,I _C =0 | 6 | | | V |
| Collector Cutoff Current | I _{CBO} | V _{CB} =60V,I _E =0 | | | 0.01 | μA |
| Collector Cutoff Current | I _{CEX} | V _{CE} =60V, V _{BE} =3V | | | 0.01 | μA |
| Emitter Cutoff Current | I _{EBO} | V _{EB} =3V,I _C =0 | | | 0.01 | μA |
| | h _{FE1} | V _{CE} =10V,I _C =150mA | 100 | | 300 | |
| DC Current Gain | h _{FE2} | V _{CE} =10V,I _C =0.1mA | 40 | | | |
| | h _{FE3} | V _{CE} =10V,I _C =500mA | 40 | | | |
| Collector-Emitter Saturation Voltage | V _{CE(sat)} | I _C =500mA,I _B =50mA | | | 1.0 | V |
| Base-Emitter Saturation Voltage | V _{BE(sat)} | I _C =500mA,I _B =50mA | | | 2.0 | V |
| Transition fraguency | £ | V _{CE} =20V,I _C =20mA | 250 | | | MHz |
| Transition frequency | f⊤ | f=100MHz | | | | IVITZ |
| Delay Time | t _d | V _{CC} =30V,I _C =150mA, | | | 10 | ns |
| Delay Time | | I _{B1} =15mA | | | | |
| Rise Time | ne t _r | V _{CC} =30V,I _C =150mA, | | | 25 | ns |
| Rise Tillie | | I _{B1} =15mA | | | | |
| Storage Time | ts | V _{CC} =30V,I _C =150mA, | | | 225 | ns |
| Storage Time | | I _{B1} = I _{B2} =15mA | | | | |
| Fall Time | t. | V _{CC} =30V,I _C =150mA, | | 6 | 60 | ns |
| Tall Tille | t _f | I _{B1} = I _{B2} =15mA | | | 00 | 113 |



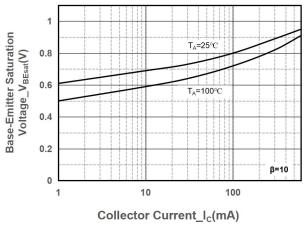
➤ Typical Performance Characteristics (T_A=25°C unless otherwise noted)

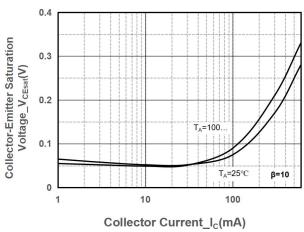




Collector Current vs. Base-Emitter Voltage

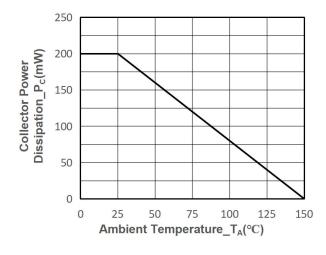
Base-Emitter Voltage DC Current Gain vs. Collector Current

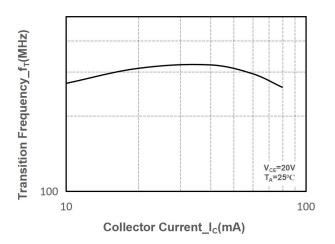




V_{BE(sat)} vs. Collector Current

V_{CE(sat)} vs. Collector Current



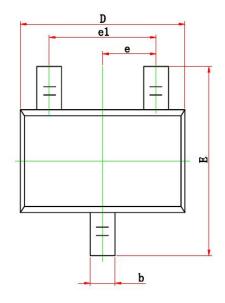


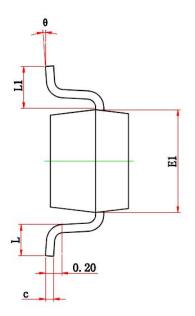
Power derating vs. Ambient temperature

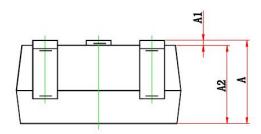
Transition Frequency vs. Collector Current



> Package Information







| Symbol | Dimensions In Millimeters | | Dimensions In Inches | | |
|--------|---------------------------|-------|----------------------|-------|--|
| | Min. | Max. | Min. | Max. | |
| Α | 0.900 | 1.100 | 0.035 | 0.043 | |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 | |
| A2 | 0.900 | 1.000 | 0.035 | 0.039 | |
| b | 0.200 | 0.400 | 0.008 | 0.016 | |
| С | 0.080 | 0.150 | 0.003 | 0.006 | |
| D | 2.000 | 2.200 | 0.079 | 0.087 | |
| E | 2.150 | 2.450 | 0.085 | 0.096 | |
| E1 | 1.150 | 1.350 | 0.045 | 0.053 | |
| е | 0.650 TYP. | | 0.026 | TYP. | |
| e1 | 1.200 | 1.400 | 0.047 | 0.055 | |
| L | 0.260 | 0.460 | 0.010 | 0.018 | |
| L1 | 0.525 REF. | | 0.021 REF. | | |
| θ | 0° | 8° | 0° | 8° | |



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